## 1. General description

PNP/PNP matched double transistors in SOT457 (SC-74) small Surface-Mounted Device (SMD) plastic package. The transistors are fully isolated internally.

### 2. Features and benefits

- Current gain matching
- Base-emitter voltage matching
- · Drop-in replacement for standard double transistors
- AEC-Q101 qualified

## 3. Applications

- Current mirror
- · Differential amplifier

## 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Per transistor								
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-	-65	V	
I <sub>C</sub>	collector current			-	-	-100	mA	
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = -5 V; I <sub>C</sub> = -2 mA; T <sub>amb</sub> = 25 °C		200	290	450		
Per device					·			
h <sub>FE1</sub> /h <sub>FE2</sub>	DC current gain matching	$V_{CE} = -5 \text{ V}; I_{C} = -2 \text{ mA}; T_{amb} = 25 \text{ °C}$	[1]	0.9	1	-		
V <sub>BE1</sub> -V <sub>BE2</sub>	base-emitter voltage matching		[2]	-	-	2	mV	

- [1] The smaller of the two values is taken as the numerator.
- [2] The smaller of the two values is subtracted from the larger value.



### 65 V, 100 mA PNP/PNP matched double transistors

# 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E1	emitter TR1		C1 B2 E2
2	B1	base TR1	<u> </u>	
3	C2	collector TR2		(TR1)
4	E2	emitter TR2		
5	B2	base TR2	TSOP6 (SOT457)	E1 B1 C2
6	C1	collector TR1		sym018

# 6. Ordering information

#### **Table 3. Ordering information**

Type number	pe number Package						
	Name	Description	Version				
BCM856DS	TSOP6	plastic, surface-mounted package (SC-74; TSOP6); 6 leads	SOT457				

## 7. Marking

#### Table 4. Marking codes

Type number	Marking code
BCM856DS	DS

#### 65 V, 100 mA PNP/PNP matched double transistors

# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transist	or		•			
V <sub>CBO</sub>	collector-base voltage	open emitter		-	-80	V
$V_{CEO}$	collector-emitter voltage	open base		-	-65	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-5	V
I <sub>C</sub>	collector current			-	-100	mA
I <sub>CM</sub>	peak collector current	t <sub>p</sub> ≤ 1 ms; single pulse		-	-200	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	250	mW
Per device			•			
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	380	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	500	K/W
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	328	K/W

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

### 65 V, 100 mA PNP/PNP matched double transistors

## 10. Characteristics

#### **Table 7. Characteristics**

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transisto	or						
I <sub>CBO</sub>	collector-base cut-off current	V <sub>CB</sub> = -30 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-15	nA
		V <sub>CB</sub> = -30 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C		-	-	-5	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = -5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = -5 V; I <sub>C</sub> = -10 μA; T <sub>amb</sub> = 25 °C		-	250	-	
		V <sub>CE</sub> = -5 V; I <sub>C</sub> = -2 mA; T <sub>amb</sub> = 25 °C		200	290	450	
V <sub>CEsat</sub>	collector-emitter	$I_C$ = -10 mA; $I_B$ = -0.5 mA; $T_{amb}$ = 25 °C		-	-50	-200	mV
saturation vo	saturation voltage	I <sub>C</sub> = -100 mA; I <sub>B</sub> = -5 mA; T <sub>amb</sub> = 25 °C		-	-200	-400	mV
V <sub>BEsat</sub> base-emitter saturation	$I_C$ = -10 mA; $I_B$ = -0.5 mA; $T_{amb}$ = 25 °C	[1]	-	-760	-	mV	
	voltage	I <sub>C</sub> = -100 mA; I <sub>B</sub> = -5 mA; T <sub>amb</sub> = 25 °C	[1]	-	-920	-	mV
$V_{BE}$	base-emitter voltage	$V_{CE}$ = -5 V; $I_{C}$ = -2 mA; $T_{amb}$ = 25 °C	[2]	-600	-650	-700	mV
		V <sub>CE</sub> = -5 V; I <sub>C</sub> = -10 mA; T <sub>amb</sub> = 25 °C	[2]	-	-	-760	mV
C <sub>c</sub>	collector capacitance	$V_{CB}$ = -10 V; $I_{E}$ = 0 A; $i_{e}$ = 0 A; $f$ = 1 MHz; $T_{amb}$ = 25 °C		-	-	2.2	pF
C <sub>e</sub>	emitter capacitance	$V_{EB}$ = -0.5 V; $I_{C}$ = 0 A; $i_{c}$ = 0 A; $f$ = 1 MHz; $T_{amb}$ = 25 °C		-	10	-	pF
f <sub>T</sub>	transition frequency	$V_{CE}$ = -5 V; $I_{C}$ = -10 mA; f = 100 MHz; $T_{amb}$ = 25 °C		100	175	-	MHz
NF	noise figure	$V_{CE}$ = -5 V; $I_{C}$ = -0.2 mA; $R_{S}$ = 2 k $\Omega$ ; f = 10 Hz to 15.7 kHz		-	1.6	-	dB
		$V_{CE}$ = -5 V; $I_{C}$ = -0.2 mA; $R_{S}$ = 2 k $\Omega$ ; B = 200 Hz; f = 1 kHz		-	3.1	-	dB
Per device						1	
h <sub>FE1</sub> /h <sub>FE2</sub>	DC current gain matching	$V_{CE}$ = -5 V; $I_{C}$ = -2 mA; $T_{amb}$ = 25 °C	[3]	0.9	1	-	
V <sub>BE1</sub> -V <sub>BE2</sub>	base-emitter voltage matching		[4]	-	-	2	mV
	1	1	1				

 $V_{\mbox{\footnotesize{BEsat}}}$  decreases by about 1.7 mV/K with increasing temperature.

 $<sup>\</sup>ensuremath{\text{V}_{\text{BE}}}$  decreases by about 2 mV/K with increasing temperature.

<sup>[2]</sup> [3] The smaller of the two values is taken as the numerator.

The smaller of the two values is subtracted from the larger value.

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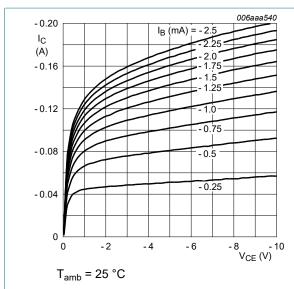
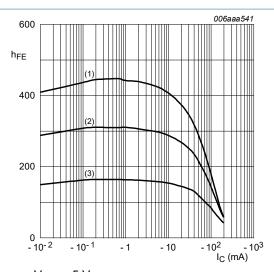


Fig. 1. Collector current as a function of collectoremitter voltage; typical values



V<sub>CE</sub> = -5 V (1) T<sub>amb</sub> = 100 °C (2) T<sub>amb</sub> = 25 °C (3) T<sub>amb</sub> = -55 °C

Fig. 2. DC current gain as a function of collector current; typical values

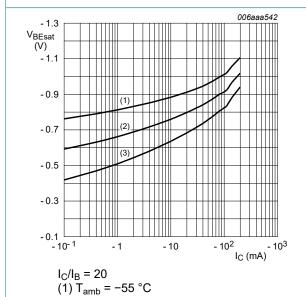
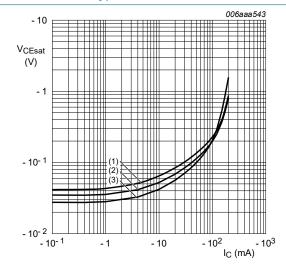


Fig. 3. Base-emitter saturation voltage as a function of collector current; typical values

(2) T<sub>amb</sub> = 25 °C

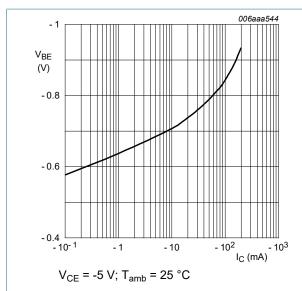
(3) T<sub>amb</sub> = 100 °C



 $I_{C}/I_{B} = 20$ (1)  $T_{amb} = 100 \,^{\circ}C$ (2)  $T_{amb} = 25 \,^{\circ}C$ (3)  $T_{amb} = -55 \,^{\circ}C$ 

Fig. 4. Collector-emitter saturation voltage as a function of collector current; typical values

#### 65 V, 100 mA PNP/PNP matched double transistors



Base-emitter voltage as a function of collector current; typical values

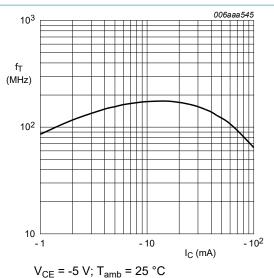
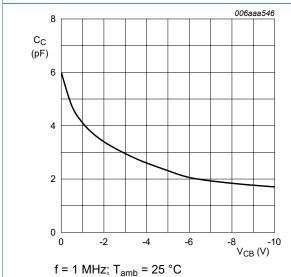
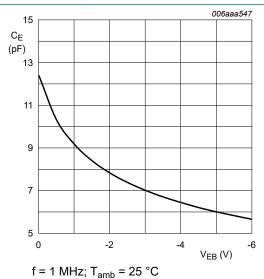


Fig. 6. Transition frequency as a function of collector current; typical values



Collector capacitance as a function of collector- Fig. 8. base voltage; typical values



Emitter capacitance as a function of emitterbase voltage; typical values

#### 11. Test information

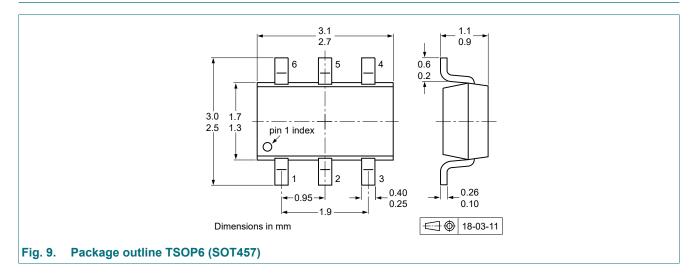
#### **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

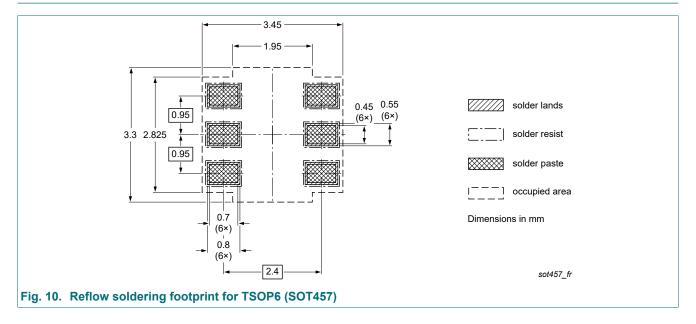
**Product data sheet** 

65 V, 100 mA PNP/PNP matched double transistors

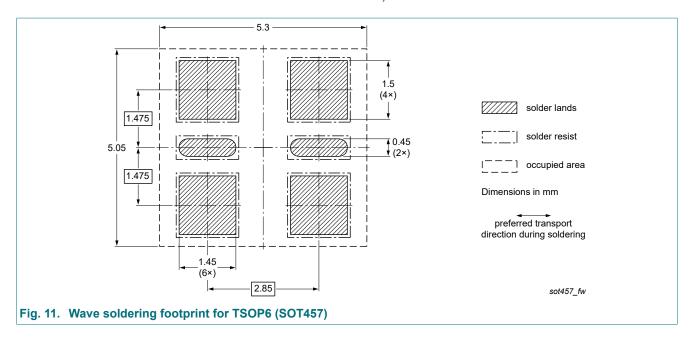
# 12. Package outline



# 13. Soldering



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### 65 V, 100 mA PNP/PNP matched double transistors

# 14. Revision history

#### Table 8. Revision history

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Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
BCM856DS v.2	20241018	Product data sheet	-	BCM856BS_BCM856D S_1			
Modifications:	<ul><li>Family data sheet reduced to single type data sheet.</li><li>Section "Packing information" removed.</li></ul>						
BCM856BS_BCM856D S_1	20080807	Product data sheet	-	-			

## 15. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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	Features and benefits

For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 18 October 2024

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